## NSN 5961-00-038-6139

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-038-6139

#### **Inclosure Material:**

Metal

## **Overall Length:**

Between 0.688 inches and 0.797 inches

## **Overall Diameter:**

Between 0.885 inches and 0.915 inches

## **Mounting Facility Quantity:**

1

#### Internal Configuration:

Junction contact

## Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Threaded stud

Features Provided:

Hermetically sealed case

#### **Overall Width Across Flats:**

Between 1.047 inches and 1.078 inches

Thread Size:

0.500 inches

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

100.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 10.0 emitter to base voltage, static, collector open

#### **Current Rating Per Characteristic:**

50.00 amperes source cutoff current

## **Power Rating Per Characteristic:**

350.0 watts small-signal input power, common-collector preset

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius case

#### **Special Features:**

Junction pattern arrangement: npn

## **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

## **Thread Series Designator:**

Unf

## **Terminal Type And Quantity:**

2 tab, solder lug and 1 wire hook

## **Specification Data:**

81349-mil-s-19500/380 government specification

Shelf Life:

NI/o

# NSN 5961-00-038-6139

Transistor - Page 2 of 2

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

